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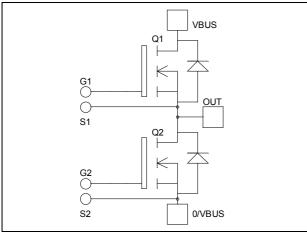


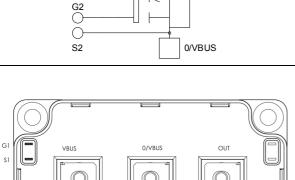




# Phase leg **MOSFET Power Module**

 $V_{DSS} = 200V$  $R_{DSon} = 4m\Omega \text{ typ } @ Tj = 25^{\circ}C$  $I_D = 372A$  (a) Tc = 25°C





#### **Application**

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### **Features**

- Power MOS 7<sup>®</sup> FREDFETs
  - Low R<sub>DSon</sub>
  - Low input and Miller capacitance
  - Low gate charge
  - Fast intrinsic reverse diode
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

#### **Benefits**

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- **RoHS Compliant**

A	haa	liita	maximum	ratings
$\Delta$	เทรก	ште	maximiim	ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		200	V
$I_D$	Canting a David Comment	$T_c = 25$ °C	372	
	Continuous Drain Current	$T_c = 80$ °C	278	Α
$I_{DM}$	Pulsed Drain current		1488	
$V_{GS}$	Gate - Source Voltage		±30	V
R <sub>DSon</sub>	Drain - Source ON Resistance		5	mΩ
$P_{D}$	Maximum Power Dissipation $T_c = 25^{\circ}C$		1250	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)		100	A
$E_{AR}$	Repetitive Avalanche Energy		50	mJ
$E_{AS}$	Single Pulse Avalanche Energy		3000	111J

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### All ratings @ $T_j = 25$ °C unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit	
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 200V$	$T_j = 25^{\circ}C$			500	^	
	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 160V$	$T_j = 125$ °C			2000	μΑ	
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 186A$			4	5	mΩ	
V <sub>GS(th)</sub>	Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 10$ mA		3		5	V	
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$				±200	nA	

**Dynamic Characteristics** 

•	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		28.9		
$C_{oss}$	Output Capacitance	$V_{DS} = 25V$		9.32		nF
$C_{rss}$	Reverse Transfer Capacitance	f = 1MHz		0.58		
$Q_{\mathrm{g}}$	Total gate Charge	$V_{GS} = 10V$		560		
$Q_{\mathrm{gs}}$	Gate – Source Charge	$V_{\text{Bus}} = 100 \text{V}$		212		пC
$Q_{gd} \\$	Gate – Drain Charge	$I_D = 372A$		268		
$T_{d(on)}$	Turn-on Delay Time	Inductive switching @ 125°C $V_{GS} = 15V$ $V_{Bus} = 133V$ $I_D = 372A$ $R_G = 1.2\Omega$		32		
$T_{\rm r}$	Rise Time			64		ns
$T_{d(off)}$	Turn-off Delay Time			88		
$T_{\mathrm{f}}$	Fall Time			116		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C $V_{GS} = 15V$ , $V_{Bus} = 133V$ $I_D = 372A$ , $R_G = 1.2\Omega$		3396		1
E <sub>off</sub>	Turn-off Switching Energy			3716		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C $V_{GS} = 15V$ , $V_{Bus} = 133V$ $I_D = 372A$ , $R_G = 1.2\Omega$		3744		T
$E_{\text{off}}$	Turn-off Switching Energy			3944		μJ

#### **Source - Drain diode ratings and characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
$I_S$	Continuous Source current		$Tc = 25^{\circ}C$			372	Α
	(Body diode)		$Tc = 80^{\circ}C$			278	Λ
$V_{\mathrm{SD}}$	Diode Forward Voltage	$V_{GS} = 0V, I_S = -372A$				1.3	V
dv/dt	Peak Diode Recovery •					5	V/ns
+	Reverse Recovery Time	$I_S = -372A$ $V_R = 133V$	$T_j = 25$ °C			230	ng
t <sub>rr</sub>	Reverse Recovery Time	$di_{S}/dt = 400A/\mu s$	$T_j = 125$ °C			450	ns
0	Barrage Barrage Change	$I_S = -372A$ $V_R = 133V$	$T_j = 25^{\circ}C$		3.6		μС
$Q_{rr}$	Reverse Recovery Charge	$v_R = 133 v$ $di_S/dt = 400 A/\mu s$	$T_j = 125$ °C		13.6		μС

• dv/dt numbers reflect the limitations of the circuit rather than the device itself.

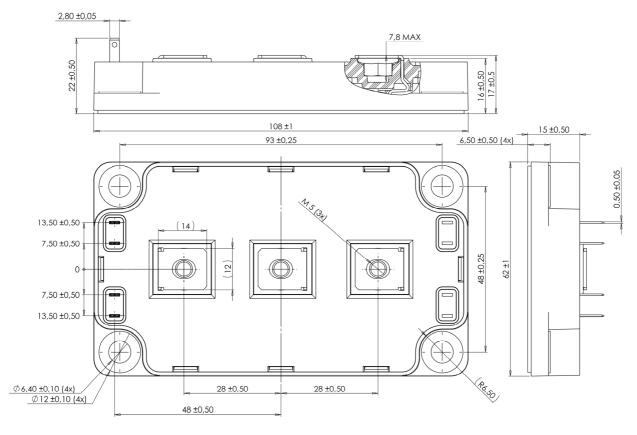
 $I_S \le -372A$   $di/dt \le 700A/\mu s$   $V_R \le V_{DSS}$   $T_i \le 150$ °C



### Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
$R_{thJC}$	Junction to Case Thermal Resistance					0.1	°C/W
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t = 1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range			-40		150	°C
T <sub>STG</sub>	Storage Temperature Range			-40		125	
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque To heatsink For terminals	To heatsink	M6	3		5	N.m
Torque		For terminals	M5	2		3.5	11.111
Wt	Package Weight					300	g

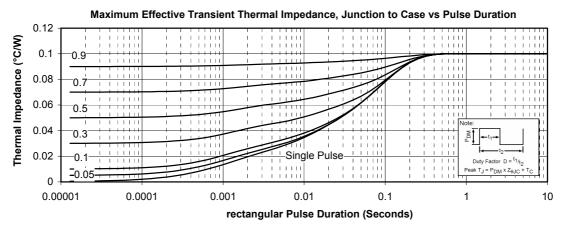
### SP6 Package outline (dimensions in mm)

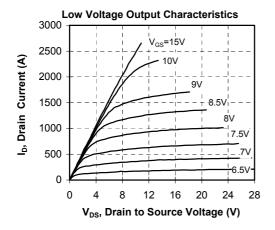


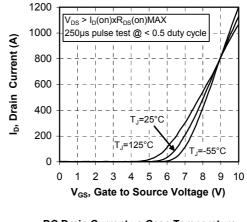
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com



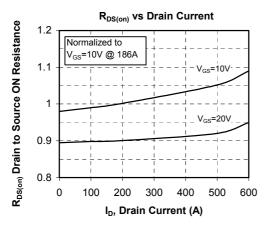
#### **Typical Performance Curve**

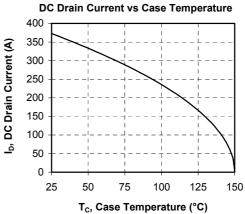




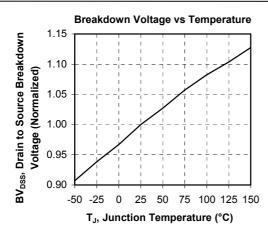


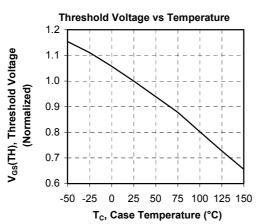
**Transfert Characteristics** 

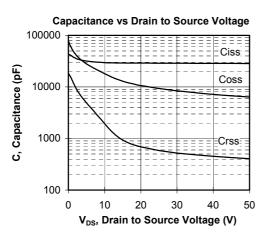


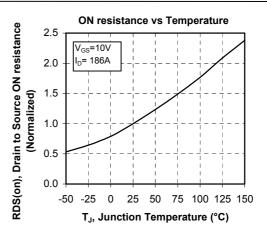


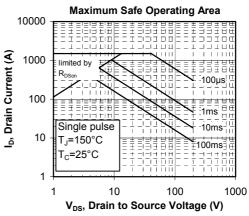


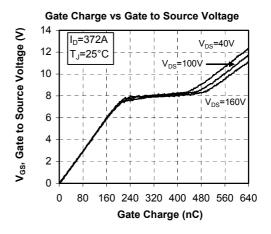






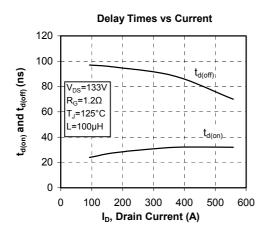


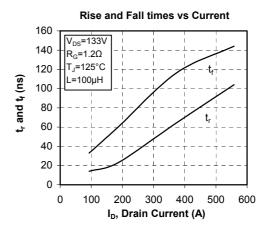


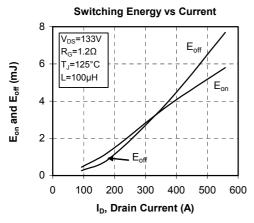


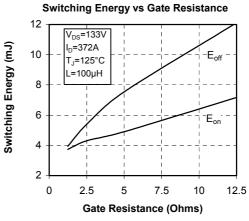
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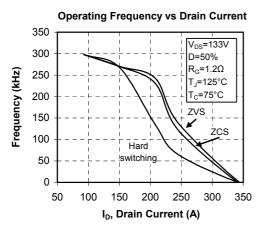


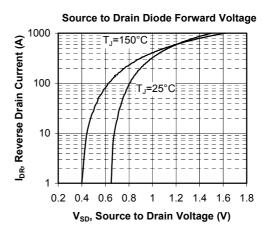














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